# MMIC, Wideband Power Tap Die

50Ω 26.5 dB DC to 50 GHz

### The Big Deal

- Ultra-Wide Bandwidth, DC to 50 GHz
- Excellent Coupling Flatness 26.5±1.4 dB typ.
- Excellent VSWR, 1.2:1 typ.

## 

HK-PT54-D+

#### **Product Overview**

Mini-Circuits' HK-PT54-D+ is a 26.5 dB Power Tap die that operates from DC to 50 GHz. It provides excellent coupling flatness over a broad bandwidth and excellent VSWR. Manufactured using IPD process, it has excellent repeatability and excellent reliability. It is ideal for lab testing applications as well as for power monitoring over wide bands in many other applications.

### **Key Features**

Feature	Advantages
Ultra Wideband, DC - 50 GHz	HK-PT54-D+ can be used in many applications saving component count. Also ideal for wideband applications such as 5G, military and instrumentation.
Excellent coupling flatness, 26.5±1.4 dB	Excellent coupling flatness yields higher accuracy.
Bi-Directional	HK-PT54-D+ can sample power from signals travelling from both the input and output port. Ideal for use in instrumentation applications for measuring ratio of the two powers (return loss)
Unpackaged die	Enables user to integrate it directly into hybrids.

## MMIC, Wideband Power Tap Die

50Ω 26.5 dB DC to 50 GHz

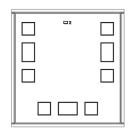
#### **Product Features**

- Wide bandwidth, DC to 50 GHz
- Excellent Coupling Flatness, 26.5±1.4 dB typ.
- Excellent VSWR, 1.2:1 typ.

#### **Typical Applications**

- 5G
- Satellite communications
- Wireless infrastructure
- Test and Measurements

### HK-PT54-D+



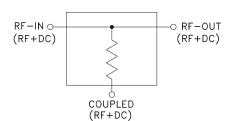
+RoHS Compliant The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

Ordering Information: Refer to Last Page

#### **General Description**

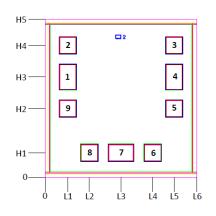
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#### Simplified Schematic and Pad description



Pad#	Function
1	RF-IN
4	RF-OUT
7	Coupled
2,3,5,6,8,9 and bottom of die	Ground

#### **Bonding Pad Position**



					Dir	ne	ensio	ns in µr	n,	Турі	cal					
L	.1	L2		L3	L4		L5	L6	1	H1	H2	F	ł3	H4	н	5
1	08	210	3	860	510	1	612	720	1	17	327	4	77	627	75	50
	TI	nicknes	s	D	ie size			ad Size 1 & 4			ad size 3,5,6,8&		F	Pad Size	e	
		100		72	0 x 750		75	5 x 115		7	75 x 75		1	15 X 7	5	

#### Electrical Specifications<sup>1</sup> at 25°C

Parameter	Frequency (GHz)	Min.	Тур.	Max.	Units
Frequency Range		DC		50	GHz
Mainline Loss	0.01-10		0.6		dB
	10-20		0.7		
	20-30		0.8		
	30-40		1.0		
	40-50		1.1		
Nominal Coupling	0.01-10		25.1		dB
	10-20		25.7		
	20-30		26.7		
	30-40		27.9		
	40-50		27.6		
Coupling Flatness (±)	0.01-50		1.4		dB
VSWR (Mainline)	0.01-10		1.15		dB
	10-20		1.21		
	20-30		1.27		
	30-40		1.25		
	40-50		1.21		
VSWR (Coupled)	0.01-10		1.17		dB
	10-20		1.20		
	20-30		1.27		
	30-40		1.35		
	40-50		1.39		

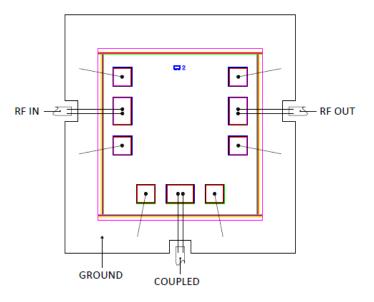
1. Electrical specifications are typical measured on characteristics on die using MPI Titan Series 150µm pitch GSG probe.

### Absolute Maximum Ratings<sup>2</sup>

Parameter	Ratings
Operating Temperature	-55°C to 105°C
Input Power	31 dBm (5 minute max.) 28 dBm (continuous)
Internal dissipation	30 dBm (5 minute max.) 27 dBm (continuous)

2. Permanent damage may occur if any of these limits are exceeded. Electrical maximum ratings are not intended for continuous normal operation.

#### **Assembly Diagram**



#### **Assembly and Handling Procedure**

1. Storage

Dice should be stored in a dry nitrogen purged desiccators or equivalent.

2. ESD

MMIC power tap dice are susceptible to electrostatic and mechanical damage. Die are supplied in antistatic protected material, which should be opened in clean room conditions at an appropriately grounded anti-static worksta tion. Devices need careful handling using correctly designed collets, vacuum pickup tips or sharp antistatic tweezers to deter ESD damage to dice.

3. Die Attach

The die mounting surface must be clean and flat. Using conductive silver filled epoxy, recommended epoxies are DieMat DM6030HK-PT/H579 or Ablestik 84-1LMISR4. Apply sufficient epoxy to meet required epoxy bond line thickness, epoxy fillet height and epoxy coverage around total die periphery. Parts shall be cured in a nitrogen filled atmosphere per manufacturer's cure condition. It is recommended to use antistatic die pick up tools only.

4. Wire Bonding

Bond pad openings in the surface passivation above the bond pads are provided to allow wire bonding to the dice gold bond pads. Thermosonic bonding is used with minimized ultrasonic content. Bond force, time, ultrasonic power and temperature are all critical parameters. Suggested wire is pure gold, 1 mil diameter. Bonds must be made from the bond pads on the die to the package or substrate. All bond wires should be kept as short as low as reasonable to minimize performance degradation due to undesirable series inductance.

#### Additional Detailed Technical Information

additional information is available on our dash board.

	Data Table	
Performance Data	Swept Graphs	
	S-Parameter (S3P Files)	
Case Style	Die	
	Quantity, Package	Model No.
Die Ordering and packaging information (Note 5)	Small, Gel - Pak: 5,10,50,100 KGD* Medium <sup>†</sup> , Partial wafer: KGD*<2070 Large <sup>†</sup> , Full wafer	HK-PT54-DG+ HK-PT54-DP+ HK-PT54-DF+
	<sup>†</sup> Available upon request contact sale	s representative
	Refer to AN-60-067	
Environmental Ratings	ENV-80	

\*Known Good Dice ("KGD") means that the dice are taken from PCM good wafer and visually inspected according to Mini-Circuits inspection criteria. While this is not definitive, it does help to provide a higher degree of confidence that dice are capable of meeting typical RF electrical parameters specified by Mini-Circuits.

#### ESD Rating\*\*

Human Body Model (HBM): Class 1B (500V) in accordance with ANSI/ESD STM 5.1 - 2001

\*\* Tested in industry standard 3.2x3.2 mm, 3-lead LTCC package. (Mini-Circuits case style DL2693-4).

#### **Additional Notes**

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
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Power Tap Die Typical Performance Data

FREQUENCY	INSERTION LOSS	COUPLING ON RF-IN	COUPLING ON RF-OUT		RETURN LOSS	
(MHz)	(dB)	(dB)	(dB)		(dB)	
				IN	OUT	CPL
10	0.59	25.06	25.04	23.83	23.69	22.29
1000	0.59	25.05	25.06	23.79	23.69	22.21
2000	0.59	25.05	25.07	23.80	23.65	22.15
5000	0.60	25.10	25.13	23.45	23.09	21.96
10000	0.65	25.30	25.32	22.51	21.76	21.36
11000	0.67	25.34	25.38	22.37	21.54	21.20
12000	0.70	25.37	25.44	22.25	21.35	21.03
13000	0.74	25.45	25.55	21.83	20.98	20.79
14000	0.74	25.59	25.67	21.32	20.41	20.62
15000	0.73	25.73	25.80	20.98	20.00	20.48
16000	0.74	25.75	25.70	20.79	19.74	20.05
17000	0.76	25.83	25.91	20.44	19.40	19.86
18000 19000	0.78 0.78	25.96 26.03	26.06 26.15	20.19 19.90	19.16 18.87	19.69 19.36
20000	0.76	26.06	26.18	19.88	18.58	18.91
21000	0.77	26.12	26.21	19.76	18.37	18.65
22000	0.79	26.28	26.36	19.63	18.18	18.47
23000	0.80	26.34	26.48	19.47	18.09	18.26
24000	0.81	26.47	26.60	19.48	18.07	18.04
25000	0.84	26.58	26.66	19.50	17.99	17.75
26000	0.86	26.59	26.71	19.33	17.89	17.48
27000	0.86	26.74	26.84	19.18	17.80	17.30
28000	0.89	27.11	27.26	19.24	17.70	17.26
29000	0.90	27.33	27.50	19.37	17.84	17.07
30000	0.91	27.58	27.75	19.54	17.95	16.85
31000	0.92	27.56	27.66	19.77	18.08	16.68
32000	0.92	27.59	27.69	19.92	17.99	16.41
33000	0.93	28.04	28.15	20.28	18.29	16.30
34000	0.93	28.16	28.26	20.28	18.59	16.18
35000	0.94	27.81	27.87	20.89	18.70	15.91
36000	0.97	28.01	28.04	20.98	18.77	15.73
38000	0.97	28.33	28.36	21.74	19.06	15.37
40000	0.97	28.18	28.30	22.52	19.48	15.12
42000	1.00	27.93	28.06	23.51	20.02	14.97
44000	1.10	28.00	28.16	24.07	20.09	15.09
46000	1.15	27.67	27.82	24.47	20.38	15.02
48000	1.24	27.25	27.38	23.20	19.37	15.54
50000	1.28	26.15	26.26	22.58	19.12	15.70

TEST CONDITIONS: INPUT POWER =0 dBm @Temperature = +25°C

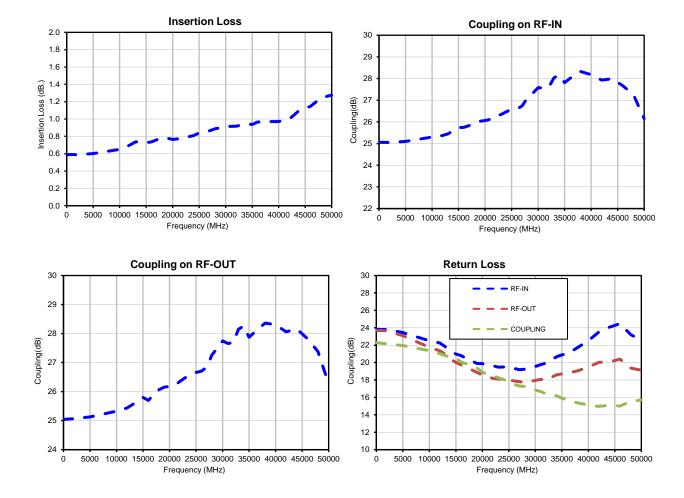




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# **Power Tap Die** *Typical Performance Curves*







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## Mini-Circuits Environmental Specifications ENV80

All Mini-Circuits products are manufactured under exacting quality assurance and control standards, and are capable of meeting published specifications after being subjected to any or all of the following physical and environmental test.

Specification	Test/Inspection Condition	Reference/Spec
perating Temperature	-40° to 85° C or -40° to 105° C $$ or -55° to 105° C Ambient Environment	Refer to Individual Model Data Sheet
orage Environment	20° to 35° C and 40 to 60% humidity (In Factory Shipped Package)	Individual Model Data Sheet